

## **DATE 07/15/1987**

- NOTES:

  1. CHAMFERED CONTOUR OPTIONAL.

  2. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.

  3. DIMENSIONING AND TOLERANCING PER ANSI VALUE 1092
- Y14.5M, 1982.
  4. CONTROLLING DIMENSION: INCH.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	1.230	1.265	31.25	32.13
В	0.250	0.270	6.35	6.85
С	0.145	0.175	3.69	4.44
D	0.015	0.020	0.38	0.51
Е	0.050 BSC		1.27 BSC	
F	0.040	0.060	1.02	1.52
G	0.100 BSC		2.54 BSC	
J	0.007	0.012	0.18	0.30
K	0.110	0.140	2.80	3.55
L	0.300 BSC		7.62 BSC	
M	0°	15°	0°	15°
N	0.020	0.040	0.51	1.01

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